Vishay Semiconductors

Hyperfast Rectifier, 8 A FRED Pt®



D-PAK (TO-252AA)

PRODUCT SUMMARY									
Package	D-PAK (TO-252AA)								
I _{F(AV)}	8 A								
V _R	200 V								
V _F at I _F	0.97 V								
t _{rr} (typ.)	23 ns								
T _J max.	175 °C								
Diode variation	Single die								

FEATURES

- Hyperfast recovery time
- 175 °C max. operating junction temperature
- Output rectification freewheeling
- Low forward voltage drop reduced Q_{rr} and soft recovery
- Low leakage current
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V _{RRM}		200	V						
Average rectified forward current	I _{F(AV)}	T _C = 156 °C	8							
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$	140	A						
Peak repetitive forward current	I _{FM}	$T_{C} = 156 \text{ °C}, f = 20 \text{ kHz}, d = 50 \%$	16							
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-				
Forward voltage	V _F	I _F = 8 A	-	0.91	0.97				
Forward voltage		I _F = 8 A, T _J = 150 °C	-	0.75	0.85				
Reverse leakage current	1	$V_R = V_R$ rated	-	-	5				
neverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ -		6	60	μA			
Junction capacitance	CT	V _R = 600 V	-	22	-	pF			
Series inductance	Ls	Measured lead to lead 5 mm from package body	-	8	-	nH			

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RoHS COMPLIANT HALOGEN FREE



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	100 A/µs, V _R = 30 V	-	23	27				
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	-	27	-					
		T _J = 25 °C		-	24	-	- ns - A			
		T _J = 125 °C	$I_F = 8 A$	-	33	-				
Deals receivers a urrent	I _{RRM}	T _J = 25 °C		-	2.3	-				
Peak recovery current		T _J = 125 °C	dl _F /dt = 200 A/µs V _B = 160 V	-	4.3	-				
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	27	-				
		T _J = 125 °C		-	70	-	nC			

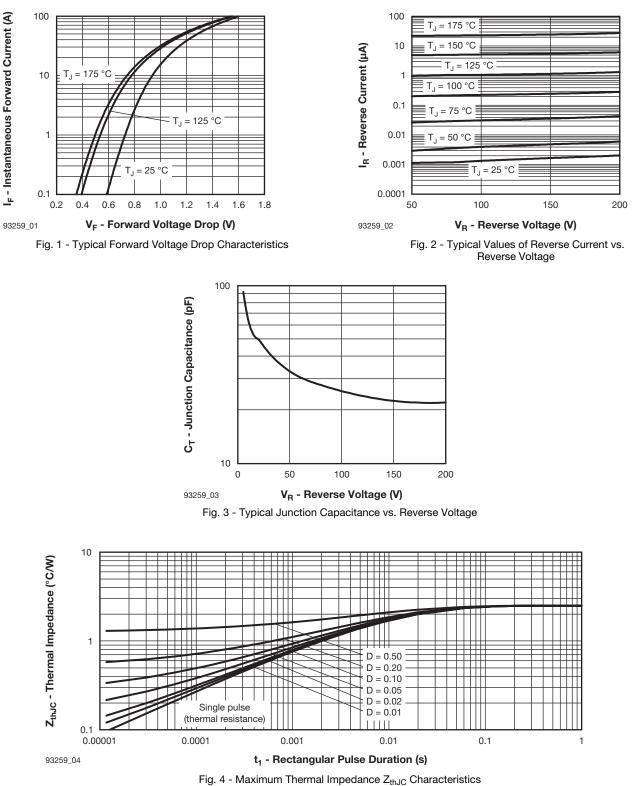
THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C				
Thermal resistance, junction to case per leg	R _{thJC}		-	1.7	2.5	°C/W				
Approximate weight				0.3		g				
Approximate weight				0.01		oz.				
Marking device		Case style D-PAK (TO-252AA)	8EWH02FN							

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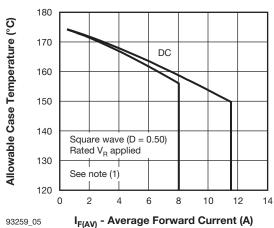
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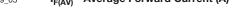
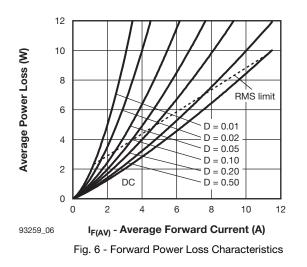


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

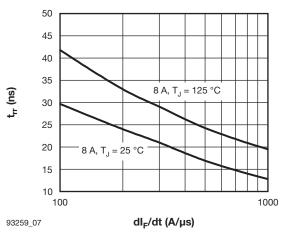


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

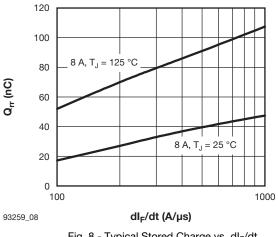


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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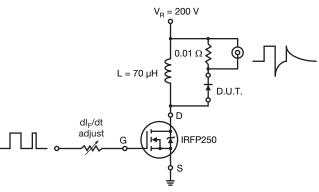


Fig. 9 - Reverse Recovery Parameter Test Circuit

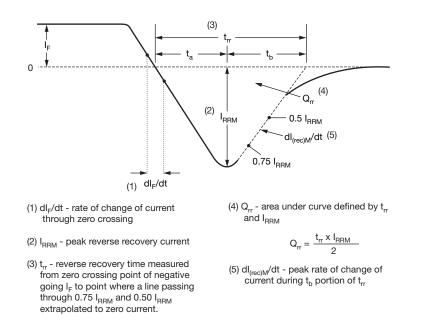


Fig. 10 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	8	Е	W	н	02	FN	TRL	-M3	
	1	2	3	4	5	6	7	8	9	
	1 -	Visl	nay Sem	niconduc	ctors pro	oduct				
	2 -	Cur	rent rati	ng (8 = 8	8 A)					
	3 - Circuit configuration:									
	E = Single diode									
	4 -									
		VV =	D-PAK							
	5 -	H =	Hyperfa	ast recov	/ery					
	6 -	Volt	tage rati	ng (02 =	= 200 V)					
	7 -	FN	= TO-25	52AA						
	8 -	• N	one = T	ube						
	TR = Tape and reel									
	 TRL = Tape and reel (left oriented) 									
	 TRR = Tape and reel (right oriented) 									
	9 -		vironmer				-			
						compli	ant and	tormina	tions lo	

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-8EWH02FN-M3	75	3000	Antistatic plastic tube							
VS-8EWH02FNTR-M3	2000	2000	13" diameter reel							
VS-8EWH02FNTRL-M3	3000	3000	13" diameter reel							
VS-8EWH02FNTRR-M3	3000	3000	13" diameter reel							

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95016							
Part marking information	www.vishay.com/doc?95176							
Packaging information	www.vishay.com/doc?95033							
SPICE model	www.vishay.com/doc?95384							

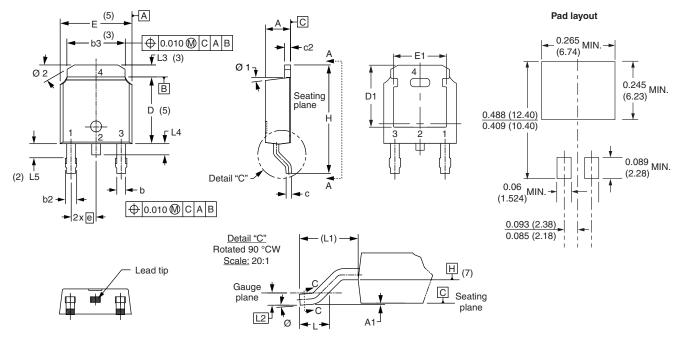
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D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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